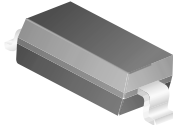




# MMSD3070



**SOD123**  
Color Band Denotes Cathode  
Top Marking:  
33

## Small Signal Diode

### Absolute Maximum Ratings\* T<sub>A</sub> = 25°C unless otherwise noted

| Symbol             | Parameter                                 | Value       | Units |
|--------------------|-------------------------------------------|-------------|-------|
| V <sub>RRM</sub>   | Maximum Repetitive Reverse Voltage        | 200         | V     |
| I <sub>F(AV)</sub> | Average Rectified Forward Current         | 200         | mA    |
| I <sub>FSM</sub>   | Non-repetitive Peak Forward Surge Current |             |       |
|                    | Pulse Width = 1.0 second                  | 1.0         | A     |
|                    | Pulse Width = 1.0 microsecond             | 2.0         | A     |
| T <sub>stg</sub>   | Storage Temperature Range                 | -55 to +150 | °C    |
| T <sub>J</sub>     | Operating Junction Temperature            | 150         | °C    |

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Thermal Characteristics

| Symbol           | Parameter                               | Value | Units |
|------------------|-----------------------------------------|-------|-------|
| P <sub>D</sub>   | Power Dissipation                       | 400   | mW    |
| R <sub>θJA</sub> | Thermal Resistance, Junction to Ambient | 312   | °C/W  |

### Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise noted

| Symbol          | Parameter             | Test Conditions                                                                              | Min | Max        | Units    |
|-----------------|-----------------------|----------------------------------------------------------------------------------------------|-----|------------|----------|
| V <sub>R</sub>  | Breakdown Voltage     | I <sub>R</sub> = 100 μA                                                                      | 200 |            | V        |
| V <sub>F</sub>  | Forward Voltage       | I <sub>F</sub> = 100 mA                                                                      |     | 1.0        | V        |
| I <sub>R</sub>  | Reverse Current       | V <sub>R</sub> = 175 V<br>V <sub>R</sub> = 175 V, T <sub>A</sub> = 150°C                     |     | 100<br>100 | nA<br>μA |
| C <sub>T</sub>  | Total Capacitance     | V <sub>R</sub> = 0, f = 1.0 MHz                                                              |     | 5.0        | pf       |
| t <sub>rr</sub> | Reverse Recovery Time | I <sub>F</sub> = I <sub>R</sub> = 30 mA,<br>I <sub>RR</sub> = 1.0 mA, R <sub>L</sub> = 100 Ω |     | 50         | ns       |

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| DOME™                | HiSeC™              | Power247™           | SuperSOT™-3      |           |
| EcoSPARK™            | I <sup>2</sup> C™   | PowerTrench®        | SuperSOT™-6      |           |
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|--------------------------|------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
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